

[TPS22994](http://www.ti.com/product/tps22994?qgpn=tps22994)

-AUGUST 2014 – REVISED SEPTEMBER 2014

TPS22994 Quad Channel Load Switch with GPIO and I²C Control

- Input Voltage: 1.0 V to 3.6 V **• Ultrathin PC**
- Low ON-State Resistance $(V_{BIAS} = 7.2 V)$ Notebook PC
	- $-$ R_{ON} = 41 mΩ at V_{IN} = 3.3 V Tablets
	- $-$ R_{ON} = 41 mΩ at V_{IN} = 1.8 V Servers
	- $-$ R_{ON} = 41 mΩ at V_{IN} = 1.5 V All-In-One PC
	- $-$ R_{ON} = 41 mΩ at V_{IN} = 1.0 V
- **3 Description** • VBIAS voltage range: 2.7 V to 17.2 V
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- ¹²C Configuration (Per Channel)
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	-
	- Programmable Output Discharge (4 options)
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- $QFN-20$ package, 3 mm x 3 mm, 0.75 mm height -40° C to 85°C.

1 Features 2 Applications

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The TPS22994 is a multi-channel, low R_{ON} load

– Suitable for 1S/2S/3S/4S Li-ion Battery

Topologies contains four N-channel MOSEFTs that can operate Topologies
1-A Max Continuous Current Per Channel
1-A Max Continuous Current Per Channel
1-A Max Continuous Current Per Channel over an input voltage range of 1.0 V to 3.6 V. The Quiescent Current
Quiescent Current **Current** switch can be controlled by I²C making it ideal for
usage with processors that have limited GPIO usage with processors that have limited GPIO – Single Channel < 12 µA available. The rise time of the TPS22994 device is internally controlled in order to avoid inrush current. Shutdown Current (All Four Channels) $< 7 \mu A$ The TPS22994 has five programmable slew rate Four 1.2-V Compatible GPIO Control Inputs ^{options}, four ON-delay options, and four quick output four 1.2-V Compatible GPIO Control Inputs discharge (QOD) resistance options.

 $-$ On/Off Control
 $-$ On/Off Control
 $-$ Programmable Slew Rate Control (5 options)
 $-$ Programmable Slew Rate Control (5 options)

GPIO control through the ONx terminals. The I²C GPIO control through the ONx terminals. The I^2C Programmable ON-delay (4 options) slave address terminals can be tied high or low to
Regrammable Output Discharge (4 options) assign seven unique device addresses.

I²C SwitchALL™ Command for Multi- The TPS22994 is available in a space-saving RUK package (0.4-mm pitch) and is characterized for channel/Multi-chip Control

Device Information[\(1\)](#page-0-0)

(1) For all available packages, see the orderable addendum at the end of the datasheet.

4 Simplified Schematic

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, **44** intellectual property matters and other important disclaimers. PRODUCTION DATA.

Product Folder Links: *[TPS22994](http://www.ti.com/product/tps22994?qgpn=tps22994)*

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6 Device Comparison Table

(1) See *[Application Information](#page-18-0)* section.

(2) This feature discharges output of the switch to GND through an internal resistor, preventing the output from floating. See Application information section.

7 Pin Configuration and Functions

Pin Functions

8 Specifications

8.1 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted)

(1) Refer to application section.

8.2 Absolute Maximum Ratings(1)

Over operating free-air temperature range (unless otherwise noted)

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute–maximum–rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to network ground pin.

(3) In applications where high power dissipation and/or poor package thermal resistance is present, the maximum ambient temperature may have to be derated. Maximum ambient temperature [TA(max)] is dependent on the maximum operating junction temperature [T_{J(max)}], the maximum power dissipation of the device in the application [PD(max)], and the junction-to-ambient thermal resistance of the part/package in the application ($_{\theta$ JA), as given by the following equation: $T_{A(max)} = T_{J(max)} - (\theta_{JA} \times P_{D(max)})$

8.3 Handling Ratings

(1) Electrostatic discharge (ESD) to measure device sensitivity and immunity to damage caused by assembly line electrostatic discharges in to the device.

(2) Level listed above is the passing level per ANSI/ESDA/JEDEC JS-001. JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.

(3) Level listed above is the passing level per EIA-JEDEC JESD22-C101. JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

8.4 Thermal Information

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, [SPRA953.](http://www.ti.com/lit/pdf/SPRA953.)

(2) For thermal estimates of this device based on PCB copper area, see the TI PCB Thermal Calculator.

8.5 Electrical Characteristics

The specification applies over the operating ambient temperature –40°C $\leq T_A \leq 85$ °C (Full) (unless otherwise noted). Typical values are for $T_A = 25^{\circ}$ C. V_{BIAS} = 7.2 V (unless otherwise noted).

Electrical Characteristics (continued)

The specification applies over the operating ambient temperature –40°C $\leq T_A \leq 85$ °C (Full) (unless otherwise noted). Typical values are for $T_A = 25^{\circ}$ C. V_{BIAS} = 7.2 V (unless otherwise noted).

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Electrical Characteristics (continued)

The specification applies over the operating ambient temperature –40°C $\leq T_A \leq 85$ °C (Full) (unless otherwise noted). Typical values are for $T_A = 25^{\circ}C$. $V_{BIAS} = 7.2$ V (unless otherwise noted).

(1) Parameter verified by design.

8.6 Switching Characteristics, V_{BIAS} = 7.2 V

Values below are typical values at $T_A = 25^{\circ}$ C. V_{BIAS} = 7.2V (unless otherwise noted).

8.7 Switching Characteristics, V_{BIAS} = 3.3 V

Values below are typical values at $T_A = 25^{\circ}$ C. V_{BIAS} = 3.3 V (unless otherwise noted).

NSTRUMENTS

Texas

A. Rise and fall times of the control signal is 100 ns.

B. All switching measurements are done using GPIO control only.

Figure 2. t_{ON}/t_{OFF} Waveforms

8.8 Typical Characteristics

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9 Detailed Description

9.1 Overview

The TPS22994 is a GPIO controllable and $I²C$ programmable, quad-channel load switch. The device comes in a 20-pin QFN package and is designed to handle up to 3.6 V and 1 A per channel (per VINx/VOUTx). The VBIAS pin of the device is designed to interface directly with battery voltages or adapter input voltages as high as 17.2 V. To increase efficiency during standby power, the device implements each channel with an N-channel MOSFET without the use of a chargepump. This allows the quiescent current ($I_{Q,VB|AS}$) to be much lower than traditional GPIO-based load switches, thus increasing efficiency during standby.

The TPS22994 can be programmed via standard $I²C$ commands. This allows the user to select between 5 slew rates, 4 on-delays, and 4 quick output discharge (QOD) options. The combination of these options allows the user to program the power sequencing for downstream modules via software. Each individual channel can also be controlled (enabling and disabling channels only) via GPIO when I²C communication is not present. The TPS22994 contains a special function called SwitchALLTM that allows multiple devices (either the TPS22993 or TPS22994) to be enabled or disabled synchronously via a single I^2C command, allowing the user to switch system power states synchronously.

9.2 Functional Block Diagram

9.3 Feature Description

9.3.1 Operating Frequency

The TPS22994 is designed to be compatible with fast-mode plus and operate up to 1 MHz clock frequency for bus communication. The device is also compatible with standard-mode (100 kHz) and fast-mode (400 kHz). This device can reside on the same bus as high-speed mode (3.4MHz) devices, but the device is not designed to for ²C commands for frequencies greater than 1 MHz. See table below for characteristics of the fast-mode plus, fast-mode, and standard-mode bus speeds.

(1) over operating free-air temperature range (unless otherwise noted)

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9.3.2 SDA/SCL Pin Configuration

The SDA and SCL pins of the device operate use an open-drain configuration, and therefore, need pull up resistors to communicate on the I²C bus. The graph below shows recommended values for max pull-up resistors (R_P) and bus capacitances (C_b) to ensure proper bus communications. The SDA and SCL pins should be pulled up to VDD through an appropriately sized R_P based on the graphs below.

9.3.3 Address (ADDx) Pin Configuration

The TPS22994 can be configured with an unique I^2C slave addresses by using the ADDx pins. There are 3 ADDx pins that can be tied high to VDD or low to GND (independent of each other) to get up to 7 different slave addresses. The ADDx pins should be tied to GND if the I²C functionality of the device is not to be used. External pull-up resistors for the ADDx are optional as the ADDx inputs are high impedance. The following table shows the ADDx pin tie-offs with their associated slave addresses (assuming an eight bit word, where the LSB is the read/write bit and the device address bits are the 7 MSB bits) :

9.3.4 On-Delay Control

Using the I²C interface, the configuration register for each channel can be set for different ON delays for power sequencing. The typical options for delay are as follows (see *[Switching Characteristics, V](#page-8-0)BIAS = 7.2 V* table):

- $00 = 11$ µs delay (default register value)
- $01 = 105$ µs delay
- $10 = 330$ µs delay
- $11 = 950$ µs delay

It is not recommended to change the delay value for the duration of the delay that is programmed when the channel is enabled (except for ON-delay setting of '00' which requires a minimum of 100µs wait time before changing the setting). This could result in erratic behavior where the output could toggle unintentionally but would eventually recover by the end of the delay time programmed at the time of channel enable.

9.3.5 Slew Rate Control

Using the I²C interface, the configuration register for each channel can be set for different slew rates for inrush current control and power sequencing. The typical options for slew rate are as follows (see Switching Characteristics table for VOUTx rise times):

 $000 = 1 \text{ }\mu\text{s/V}$ $001 = 150 \text{ }\mu\text{s/V}$ $010 = 250 \text{ }\mu\text{s/V}$ 011 = 460 µs/V (default register value) $100 = 890$ us/V 101 = invalid slew rate $110 =$ invalid slew rate $111 =$ reserved

9.3.6 Quick Output Discharge (QOD) Control

Using the I^2C interface, the configuration register for each channel can be set for different output discharge resistors. The typical options for QOD are as follows (see Electrical Characteristics table):

 $00 = 110$ Ω $01 = 490$ Ω 10 = 951 Ω (default register value) $11 = No QOD$ (high impedance)

9.3.7 Mode Registers

Using the I^2C interface, the mode registers can be programmed to the desired on/off status for each channel. The contents of these registers are copied over to the control registers when a SwitchALL™ command is issued, allowing all channels of the device to transition to their desired output states synchronously. See the I²C Protocol section and the Application Scenario section for more information on how to use the mode registers in conjunction with the SwitchALL™ command.

9.3.8 SwitchALL™ Command

¹²C controlled channels can respond to a common slave address. This feature allows multiple load switches on the same I²C bus to respond simultaneously. The SwitchALL™ address is **EEh**. During a SwitchALL™ command, the lower four bits (bits 0 through 3) of the mode register is copied to the lower four bits (bits 0 through 3) of the control register. The mode register to be invoked is referenced in the body of the SwitchALL™ command. The structure of the SwitchALL™ command is as follows (as shown in [Figure 43](#page-20-0)): <start><SwitchALL™ addr><mode addr><stop>. See the I²C Protocol section and the Application Scenario section for more information on how to use the SwitchALL™ command in conjunction with the mode registers.

SCL ,,,,,,,,,,,,,,,,, ,,,,,,,,,,,,,,,,,,,

Figure 43. Composition of SwitchALL™ Command

9.3.9 V_{DD} Supply For I²C Operation

The SDA and SCL pins of the device must be pulled up to the VDD voltage of the device for proper I²C bus communication. See *[Recommended Operating Conditions](#page-4-1)* for VDD operating range.

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9.3.10 Input Capacitor (Optional)

To limit the voltage drop on the input supply caused by transient in-rush currents when the switch turns on into a discharged load capacitor or short-circuit, a capacitor needs to be placed between V_{IN} and GND. A 1- μ F ceramic capacitor, C_{IN} , placed close to the pins, is usually sufficient. Higher values of C_{IN} can be used to further reduce the voltage drop during high-current application. When switching heavy loads, it is recommended to have an input capacitor about 10 times higher than the output capacitor to avoid excessive voltage drop. For the fastest slew rate setting of the device, a CIN to CL ratio of at least 100 to 1 is recommended to avoid excessive voltage drop.

9.3.11 Output Capacitor (Optional)

Due to the integrated body diode of the NMOS switch, a C_{IN} greater than C_{L} is highly recommended. A C_{L} greater than C_{IN} can cause V_{OUT} to exceed V_{IN} when the system supply is removed. This could result in current flow through the body diode from V_{OUT} to V_{IN}. A C_{IN} to C_L ratio of at least 10 to 1 is recommended for minimizing V_{IN} dip caused by inrush currents during startup. For the fastest slew rate setting of the device, a CIN to CL ratio of at least 100 to 1 is recommended to minimize V_{IN} dip caused by inrush currents during startup.

9.3.12 I²C Protocol

The following section will cover the standard ${}^{12}C$ protocol used in the TPS22994. In the ${}^{12}C$ protocol, the following basic blocks are present in every command (except for the SwitchALL™ command):

- Start/stop bit marks the beginning and end of each command.
- Slave address $-$ the unique address of the slave device.
- Sub address this includes the register address and the auto-increment bit.
- Data byte data being written to the register. Eight bits must always be transferred even if a single bit is being written or read.
- Auto-increment bit setting this bit to '1' turns on the auto-increment functionality; setting this bit to '0' turns off the auto-increment functionality.
- Write/read bit this bit signifies if the command being sent will result in reading from a register or writing to a register. Setting this bit to '0' signifies a write, and setting this bit to '1' signifies a read.
- Acknowledge bit this bit signifies if the master or slave has received the preceding data byte.

9.3.12.1 Start and Stop Bit

In the I^2C protocol, all commands contain a START bit and a STOP bit. A START bit, defined by high to low transition on the SDA line while SCL is high, marks the beginning of a command. A STOP bit, defined by low to high transition on the SDA line while SCL is high, marks the end of a command. The START and STOP bits are generated by the master device on the ¹²C bus. The START bit indicates to other devices that the bus is busy, and some time after the STOP bit the bus is assumed to be free.

9.3.12.2 Auto-increment Bit

The auto-increment feature in the I²C protocol allows users to read from and write to consecutive registers in fewer clock cycles. Since the register addresses are consecutive, this eliminates the need to resend the register address. The I²C core of the device automatically increments the register address pointer by one when the autoincrement bit is set to '1'. When this bit is set to '0', the auto-increment functionality is disabled.

9.3.12.3 Write Command

During the write command, the write/read bit is set to '0', signifying that the register in question will be written to. [Figure 44](#page-21-0) the composition of the write protocol to a *single* register:

Number of clock cycles for single register write: 29

If multiple consecutive registers must be written to, a short-hand version of the write command can be used. Using the auto-increment functionality of I²C, the device will increment the register address after each byte. [Figure 45](#page-22-0) shows the composition of the write protocol to multiple *consecutive* registers:

SCL

Figure 45. Data Write to Consecutive Registers

Number of clock cycles for consecutive register write: $20 + (Number of registers) \times 9$

The write command is always ended with a STOP bit after the desired registers have been written to. If multiple non-consecutive registers must be written to, then the format in [Figure 44](#page-21-0) must be followed.

9.3.12.4 Read Command

During the read command, the write/read bit is set to '1', signifying that the register in question will be read from. However, a read protocol includes a "dummy" write sequence to ensure that the memory pointer in the device is pointing to the correct register that will be read. Failure to precede the read command with a write command may result in a read from a random register. [Figure 46](#page-22-1) shows the composition of the read protocol to a single register:

Figure 46. Data Read to a Single Register

Number of clock cycles for single register read: 39

If multiple registers must be read from, a short-hand version of the read command can be used. Using the auto-increment functionality of I²C, the device will increment the register address after each byte. [Figure 47](#page-22-2) shows the composition of the read protocol to multiple consecutive registers:

Number of clock cycles for consecutive register write: $30 + (Number of registers) \times 9$

The read command is always ended with a STOP bit after the desired registers have been read from. If multiple non-consecutive registers must be read from, then the format in [Figure 46](#page-22-1) must be followed.

9.3.12.5 SwitchALLTM Command

The SwitchALLTM command allows multiple devices in the same I^2C bus to respond synchronously to the same command from the master. Every TPS22994 device has a shared address which allows for multiple devices to respond or execute a pre-determined action with a single command. [Figure 48](#page-23-1) shows the composition of the SwitchALL[™] command:

SCL

Figure 48. SwitchALLTM Command Structure

Number of clock cycles for a SwitchALL™ command: 20

9.4 Device Functional Modes

9.4.1 I²C Control

When power is applied to VBIAS, the device comes up in its default mode of GPIO operation where the channel outputs can be controlled solely via the ON pins. At any time, if SDA and SCL are present and valid, the device can be configured to be controlled via I^2C (if in GPIO control) or GPIO (if in I^2C control).

The control register (address **05h**) can be configured for GPIO or I²C enable on a per channel basis.

9.4.2 GPIO Control

There are four ON pins to enable/disable the four channels. Each ON pin controls the state of the switch by default upon power up. Asserting ON high enables the switch. ON is active high and has a low threshold, making it capable of interfacing with low-voltage signals. The ON pin is compatible with standard GPIO logic threshold. It can be used with any microcontroller with 1.2 V or higher voltage GPIO.

9.5 Register Map

Configuration registers (default register values shown below)

Channel 2 configuration register (Address: **02h**)

Channel 3 configuration register (Address: **03h**)

Channel 4 configuration register (Address: **04h**)

Control register (default register values shown below)

Control register (Address: **05h**)

Mode registers (default register values shown below)

Mode1 (Address: **06h**)

Mode2 (Address: **07h**)

Mode3 (Address: **08h**)

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Mode4 (Address: **09h**)

Mode5 (Address: **0Ah**)

Mode6 (Address: **0Bh**)

Mode7 (Address: **0Ch**)

Mode8 (Address: **0Dh**)

Mode9 (Address: **0Eh**)

Mode10 (Address: **0Fh**)

Mode11 (Address: **10h**)

Mode12 (Address: **11h**)

10 Applications and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

This section will cover applications of I^2C in the TPS22994. Registers discussed here are specific to the TPS22994.

10.1.1 Input Capacitor (Optional)

To limit the voltage drop on the input supply caused by transient in-rush currents when the switch turns on into a discharged load capacitor or short-circuit, a capacitor needs to be placed between V_{IN} and GND. A 1- μ F ceramic capacitor, C_{IN} , placed close to the pins, is usually sufficient. Higher values of C_{IN} can be used to further reduce the voltage drop during high-current application. When switching heavy loads, it is recommended to have an input capacitor about 10 times higher than the output capacitor to avoid excessive voltage drop. For the fastest slew rate setting of the device, a CIN to CL ratio of at least 100 to 1 is recommended to avoid excessive voltage drop.

10.1.2 Output Capacitor (Optional)

Due to the integrated body diode of the NMOS switch, a C_{IN} greater than C_L is highly recommended. A C_L greater than C_{IN} can cause V_{OUT} to exceed V_{IN} when the system supply is removed. This could result in current flow through the body diode from V_{OUT} to V_{IN}. A C_{IN} to C_L ratio of at least 10 to 1 is recommended for minimizing V_{IN} dip caused by inrush currents during startup. For the fastest slew rate setting of the device, a CIN to CL ratio of at least 100 to 1 is recommended to minimize V_{IN} dip caused by inrush currents during startup.

10.1.3 Switch from GPIO Control to I²C Control (and vice versa)

The TPS22994 can be switched from GPIO control to I^2C (and vice versa) mode by writing to the control register of the device. Each device has a single control register and is located at register address 05h. The register's composition is as follows:

Control register (Address: **05h**)

Figure 49. Control Register Composition

The higher four bits of the control register dictates if the device is in GPIO control (bit set to '0') or I²C control (bit set to '1'). The transition from GPIO control to I^2C control can be made with a single write command to the control register. See [Figure 44](#page-21-0) for the composition of a single write command. It is recommended that the channel of interest is transitioned from GPIO control to I^2C control with the first write command and followed by a second write command to enable the channel via 12 C control. This will ensure a smooth transition from GPIO control to I^2C control.

10.1.4 Configuration of Configuration Registers

The TPS22994 contains four configuration registers (one for each channel) and are located at register addresses **01h** through **04h**. The register's composition is as follows (single channel shown for clarity):

Channel 1 configuration register (Address: **01h**)

Figure 50. Configuration Register Composition

10.1.4.1 Single Register Configuration

A single configuration register can be written to using the write command sequence shown in [Figure 44.](#page-21-0)

Multiple register writes to non-consecutive registers is treated as multiple single register writes and follows the same write command as that of a single register write as shown in [Figure 44.](#page-21-0)

10.1.4.2 Multi-register Configuration (Consecutive Registers)

Multiple consecutive configuration registers can be written to using the write command sequence shown in [Figure 45](#page-22-0).

10.1.5 Configuration of Mode Registers

The TPS22994 contains twelve mode registers located at register addresses **06h** through **11h**. These mode registers allow the user to turn-on or turn-off multiple channels in a single TPS22994 or multiple channels spanning multiple TPS22994 devices with a single SwitchALLTM command.

For example, an application may have multiple power states (e.g. sleep, active, idle, etc.) as shown in [Figure 51](#page-27-0).

Figure 51. Application Example of Power States

In each of the different power states, different combinations of channels may be on or off. Each power state may be associated with a single mode register (Mode1, Mode2, etc.) across multiple TPS22994 as shown in [Table 2](#page-27-1). For example, with 7 quad-channel devices, up to 28 rails can be enabled/disabled with a single SwitchALLTM command.

The contents of the lower four bits of the mode register is copied into the lower four bits of the control register during an SwitchALL™ command. The address of the mode register to be copied is specified in the SwitchALL™ command (see [Figure 48](#page-23-1) for the structure of the SwitchALLTM command). By executing a SwitchALLTM command, the application will apply the different on/off combinations for the various power states with a single command rather than having to turn on/off each channel individually by re-configuring the control register. This reduces the latency and allows the application to control multiple channels synchronously. The example above shows the application using three mode registers, but the TPS22994 contains twelve mode registers, allowing for up to twelve power states.

The mode register's composition is as follows (single mode register shown for clarity):

Mode1 (Address: **06h**)

The lower four bits of the mode registers are copied into the lower four bits of the control register during an allcall command.

10.1.6 Turn-on/Turn-off of Channels

By default upon power up VBIAS, all the channels of the TPS22994 are controlled via the ONx pins. Using the ²C interface, each channel be controlled via ²C control as well. The channels of the TPS22994 can also be switched on or off by writing to the control register of the device. Each device has a single control register and is located at register address **05h**. The register's composition is as follows:

Control Register (Address: **05h**)

Figure 53. Control Register Composition

The lower four bits of the control register dictate if the channels of the device are off (bit set to '0') or on (bit set to '1') during I²C control. The transition from off to on can be made with a single write command to the control register. See [Figure 44](#page-21-0) for the composition of a single write command.

10.2 Typical Application

10.2.1 Tying Multiple Channels in Parallel

Two or more channels of the device can be tied in parallel for applications that require lower R_{ON} and/or more continous current. Tying two channels in parallel will result in half of the R_{ON} and two times the I_{MAX} capability. Tying three channels in parallel will result in one-third of the R_{ON} and three times the I_{MAX} capability. Tying four channels in parallel will result in one-fourth of the R_{ON} and four times the I_{MAX} capability. For the channels that are tied in parallel, it is recommended that the ONx pins be tied together for synchronous control of the channels when in GPIO control. In I²C control, all four channels can be enabaled or disabled synchronously by writing to the control register of the device. [Figure 54](#page-29-2) shows an application example of tying all four channels in parallel.

Figure 54. Parallel Channels

10.2.1.1 Design Requirements

Refer to *[Design Requirements](#page-31-0)* .

10.2.1.2 Detailed Design Procedure

 ΔV = voltage drop from VINx to VOUTx

Refer to *[Detailed Design Procedure](#page-31-1)*.

The only difference between single channel and multiple channels in parallel is the resulting R_{ON} and voltage drop from VINx to VOUTx. Thus, the design procedure is identical to *[Detailed Design Procedure](#page-31-1)*. The VINx to VOUTx voltage drop in the device is determined by the R_{ON} of the device and the load current. The R_{ON} of the device depends upon the VIN conditions of the device. Refer to the R_{ON} specification of the device in the *[Electrical Characteristics](#page-5-1)* table of this datasheet. Once the R_{ON} of the device is determined based upon the VINx conditions, use the following equation to calculate the VINx to VOUTx voltage drop:

 $\Delta V = I_{\rm LOAD} \times (R_{\rm ON}/K)$ (1)

 I_{LOAD} = load current

Where:

 R_{ON} = On-resistance of the device for a specific V_{IN} $K =$ number of channels in parallel $(2, 3, 0r 4)$

An appropriate I_{LOAD} must be chosen such that the I_{MAX} specification per channel of the device is not violated.

10.2.1.3 Application Curves

Refer to *[Application Curves](#page-32-0)*.

Typical Application (continued)

10.2.2 Cold Boot Programming of All Registers

Since the TPS22994 has a digital core with volatile memory, upon power cycle of the VBIAS pin, the registers will revert back to their default values (see register map for default values). Therefore, the application must reprogram the configuration registers, control register, and mode registers if non-default values are desired. The TPS22994 contains 17 programmable registers (4 configuration registers, 1 control register, 12 mode registers) in total.

During cold boot when the microcontroller and the I^2C bus is not yet up and running, the channels of the TPS22994 can still be enabled via GPIO control. One method to achieve this is to tie the ONx pin to the respective VINx pin for the channels that need to turn on by default during cold boot. With this method, when VINx is applied to the TPS22994, the channel will be enabled as well. Once the I^2C bus is active, the channel can be switched over to 1^2C control to be disabled. See [Figure 55](#page-30-0) for an example of how the ONx pins can be tied to VINx for default enable during cold boot.

Figure 55. Cold Boot Programming

10.2.2.1 Design Requirements

Refer to *[Design Requirements](#page-31-0)*.

10.2.2.2 Detailed Design Procedure

Refer to *[Design Requirements](#page-31-0)*.

10.2.2.3 Application Curves

Refer to *[Application Curves](#page-32-0)*.

Typical Application (continued)

10.2.3 Power Sequencing Without I²C

It is also possible to power sequence the channels of the device during a cold boot when there is no I²C bus present for control. One method to accomplish this it to tie the VOUT of one channel to the ON pin of the next channel in the sequence. For example, if the desired power up sequence is VOUT3, VOUT1, VOUT2, and VOUT4 (in that order), then the device can be configured for GPIO control as shown in [Figure 56](#page-31-2). The device will power up with default slew rate, ON-delay, and QOD values as specified in the register map.

Figure 56. Power Sequencing Without I²C Schematic

10.2.3.1 Design Requirements

10.2.3.1.1 Reading From the Registers

Reading any register from the TPS22994 follows the same standard I²C read protocol as outlined in the I²C Protocol section of this datasheet.

For this design example, use the following as the input parameters:

10.2.3.2 Detailed Design Procedure

To begin the design process, the designer needs to know the following:

- V_{INx} voltage
- **Load Current**

10.2.3.2.1 VIN to VOUT Voltage Drop

(3)

The VINx to VOUTx voltage drop in the device is determined by the R_{ON} of the device and the load current. The R_{ON} of the device depends upon the VIN conditions of the device. Refer to the R_{ON} specification of the device in the *[Electrical Characteristics](#page-5-1)* table of this datasheet. Once the R_{ON} of the device is determined based upon the VINx conditions, use [Equation 2](#page-32-1) to calculate the VINx to VOUTx voltage drop:

$$
\Delta V = I_{\text{LOAD}} \times R_{\text{ON}} \tag{2}
$$

Where:

ΔV = voltage drop from VINx to VOUTx

 I_{LOAD} = load current

 R_{ON} = On-resistance of the device for a specific V_{IN}

An appropriate I_{LOAD} must be chosen such that the I_{MAX} specification of the device is not violated.

10.2.3.2.2 Inrush Current

To determine how much inrush current will be caused by the $C₁$ capacitor, use [Equation 3](#page-32-2):

$$
I_{INRUSH} = C_L \times \frac{dV_{OUT}}{dt}
$$

Where:

 I_{INRUSH} = amount of inrush caused by C_L

 C_1 = capacitance on VOUTx

 $dt =$ rise time in VOUT during the ramp up of VOUTx when the device is enabled

 dV_{OUT} = change in VOUT during the ramp up of VOUTx when the device is enabled

An appropriate C_L value should be placed on VOUTx such that the I_{MAX} specifications of the device are not violated.

10.2.3.3 Application Curves

[TPS22994](http://www.ti.com/product/tps22994?qgpn=tps22994)

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11 Layout

11.1 Board Layout

- VINx and VOUTx traces should be as short and wide as possible to accommodate for high current.
- Use vias under the exposed thermal pad for thermal relief for high current operation.
- The VINx terminals should be bypassed to ground with low ESR ceramic bypass capacitors. The typical recommended bypass capacitance is 1-µF ceramic with X5R or X7R dielectric. This capacitor should be placed as close to the device terminals as possible.
- The VOUTx terminals should be bypassed to ground with low ESR ceramic bypass capacitors. The typical recommended bypass capacitance is one-tenth of the VIN bypass capacitor of X5R or X7R dielectric rating. This capacitor should be placed as close to the device terminals as possible.
- The VBIAS terminal should be bypassed to ground with low ESR ceramic bypass capacitors. The typical recommended bypass capacitance is 0.1-µF ceramic with X5R or X7R dielectric.
- The VDD terminal should be bypassed to ground with low ESR ceramic bypass capacitors. The typical recommended bypass capacitance is 0.1-µF ceramic with X5R or X7R dielectric.
- ADDx pins should be tied high to VDD through a pull-up resistor or tied low to GND through a pull-down resistor.

The maximum IC junction temperature should be restricted to 125°C under normal operating conditions. To calculate the maximum allowable power dissipation, $P_{D(max)}$ for a given output current and ambient temperature, use the following equation:

$$
P_{\text{D(max)}}=\frac{T_{\text{J(max)}}-T_{\text{A}}}{\Theta_{\text{JA}}}
$$

Where:

 $P_{D(max)}$ = maximum allowable power dissipation

 $T_{J(max)}$ = maximum allowable junction temperature (125°C for the TPS22994)

 T_A = ambient temperature of the device

 Θ_{JA} = junction to air thermal impedance. See Thermal Information section. This parameter is highly dependent upon board layout.

The figure below shows an example of a layout.

(4)

EXAS **STRUMENTS**

12 Device and Documentation Support

12.1 Trademarks

SwitchALL is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

12.2 Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.3 Glossary

[SLYZ022](http://www.ti.com/lit/pdf/SLYZ022) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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TEXAS

TAPE AND REEL INFORMATION

ISTRUMENTS

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

Pack Materials-Page 1

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PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

PACKAGE OUTLINE

RUK0020B WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

RUK0020B WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

RUK0020B WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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